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Fermi surface evolution of Na-doped PbTe studied through density functional theory calculations and Shubnikov-de Haas measurements

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We present a combined experimental and theoretical study of the evolution of the low-temperature Fermi surface of lead telluride, PbTe, when holes are introduced through sodium substitution on the lead site. Our Shubnikov-de-Haas measurements for samples with carrier concentrations up to $9.4 \times 10^{19} \text{ cm}^{-3}$ (0.62 Na atomic %) show the qualitative features of the Fermi surface evolution (topology and effective mass) predicted by our density functional (DFT) calculations within the generalized gradient approximation (GGA): we obtain perfect ellipsoidal L-pockets at low and intermediate carrier concentrations, evolution away from ideal ellipsoidicity for the highest doping studied, and cyclotron effective masses increasing monotonically with doping level, implying deviations from perfect parabolicity throughout the whole band. Our measurements show, however, that standard DFT calculations underestimate the energy difference between the L-point and Σ -line valence band maxima, since our data are consistent with a single-band Fermi surface over the entire doping range studied, whereas the calculations predict an occupation of the Σ -pockets at higher doping. Our results for low and intermediate compositions are consistent with a non-parabolic Kane-model dispersion, in which the L-pockets are ellipsoids of fixed anisotropy throughout the band, but the effective masses depend strongly on Fermi energy.

I. INTRODUCTION

Lead telluride, PbTe, is a widely known thermoelectric material and a narrow-gap semiconductor, which can be degenerately doped by either Pb (hole-doping) or Te (electron-doping) vacancies, or by introduction of acceptor or donor impurities 1-3. Such impurity dopants have been shown to enhance the thermoelectric figure of merit, zT, from 0.8 to 1.4 for the case of sodium doping⁴⁻⁶, and to 1.5 for doping with thallium^{4,7}. Tl is also the only dopant known to date that leads to a superconducting ground state in PbTe; remarkably its maximum critical temperature of $T_c=1.5$ K is almost an order of magnitude higher than other superconducting semiconductors with similar carrier density⁸⁻¹². Understanding the physical origin of these enhanced properties and their dependence on the choice of dopant chemistry requires a detailed knowledge of the electronic structure, in particular its evolution with changes in dopant and carrier concentrations.

The valence band of PbTe has two maxima, located at the L point and close to the mid-point of the Σ highsymmetry line (we call this the Σ_m point) of the Brillouin Zone (see Fig. 1). The enhancement of zT with doping has been recently suggested to be at least in part associated with a decrease in the effective dimensionality of parts of the Fermi surface as the Σ_m pockets connect (Fig. 2)¹³. For the case of superconductivity, an increase of the density of states at the Tl concentration for which superconductivity emerges, as a consequence of the appearance of an additional band, has been invoked as a possible explanation for the enhanced T_c^{9} . Such hypotheses can be tested by a direct experimental determination of the Fermi surface topology and its evolution with carrier concentration. To date, such studies have been limited to quantum oscillation measurements performed in the low carrier concentration regime $(p \leq 1.1 \times 10^{19} \text{ cm}^{-3}$ for full topology)^{14,15}, although the enhanced thermoelectric and superconducting properties occur at considerably higher carrier concentrations. A direct measurement of the Fermi surface characteristics for these higher carrier densities is clearly needed.

In this paper we present the results of a detailed computational and experimental study of the fermiology of *p*-type Na-doped PbTe ($Pb_{1-x}Na_xTe$), with carrier concentrations up to $9.4 \times 10^{19} \text{cm}^{-3}$, obtained via density functional theory (DFT) calculations of the electronic structure, and measurements of quantum oscillations in magnetoresistance for fields up to 35 T. These measurements enable a direct characterization of the Fermi surface morphology and quasiparticle effective mass for values of the Fermi energy that far exceed those available by self-doping from Pb vacancies. Our main findings are: (i) At low temperatures, the Fermi surface is formed from eight half ellipsoids at the L points (the L-pockets) with their primary axes elongated along the [111] directions. The Fermi surface is derived from a single band up to the highest carrier concentration measured, $9.4 \times 10^{19} \text{cm}^{-3}$. (ii) The L-pockets are well described by a perfect ellipsoidal model up to a carrier concentration of $6.3 \times$ 10^{19}cm^{-3} . For a carrier concentration of $9.4 \times 10^{19} \text{cm}^{-3}$. subtle deviations from perfect ellipsoidicity can be re-

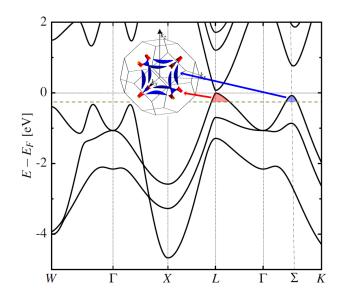


FIG. 1. (Color online) Energy dispersion for stoichiometric PbTe along the high symmetry directions of the FCC Brillouin zone, calculated in this work using density functional theory (DFT) (for details see text). A direct gap, underestimated compared with experiment as is usual in DFT calculations, is observed at the L point, and a second valence band maximum occurs along the Σ high-symmetry line. A representative Fermi surface, which emerges as the Fermi energy is shifted into the valence band by Pb vacancies or hole-dopant impurities, is shown in the inset. For the choice of Fermi level shown (green-dashed line), the Fermi surface contains eight half-ellipsoids (shaded in red) centered at the L-point and oriented along the [111] directions (L-pockets), and twelve Σ pockets (shaded in blue) centered close to the mid-point of the [110] Σ line and oriented along the [100] directions.

solved. These deviations are qualitatively consistent with those predicted by the band structure calculations.

(iii) The effective cyclotron masses increase monotonically with carrier concentration for all high-symmetry directions, implying that the L band is not well described by a perfect parabolic model for any carrier density. This evolution is also consistent with the predictions from our band structure calculations.

(iv) Although the qualitative evolution of the Fermi surface topology with carrier concentration is correctly predicted by band structure calculations, these calculations underestimate the band offset (between the top of the L-band and the top of the Σ_m -band).

Before detailing our experiments, we emphasize that our measurements are made in the low temperature regime and caution should be exercised before extrapolating the results to different temperature regimes. Quantum oscillations characterize the low-temperature properties of a material, and due to the exponential damping factor, they cannot be observed above approximately 60 K in Na-doped PbTe. Hence, we do not claim that our first three findings outlined above necessarily remain valid at higher temperatures. In particular, earlier experimental studies, based on magnetoresistance and Hall coefficient measurements¹⁶, have indicated an appreciable temperature dependence of both the band gap and the band offset (between L and Σ band maxima) in PbTe. Additionally, recent angle resolved photo emission spectroscopy (ARPES) experiments have provided evidence for the convergence of the top of these two bands at high temperatures, becoming degenerate at $\sim 800 \text{ K}^{17-19}$. The current measurements provide a definitive determination of the morphology of the bulk Fermi surface at low temperatures, and hence provide an important point of comparison for band structure calculations, but additional measurements based on a technique that is less sensitive to the quasiparticle relaxation rate, such as ARPES, are required in order to determine whether the Σ -pocket remains unoccupied at higher temperatures for the carrier concentrations studied here.

II. FIRST-PRINCIPLES CALCULATIONS

To provide a baseline with which to compare our experimental data, we first show density functional theory (DFT) calculations of the electronic structure of PbTe with and without doping. An accurate description of this compound within DFT is very challenging; in particular, the computed band structure is highly sensitive to the choice of volume, the exchange-correlation functional, and whether or not spin-orbit coupling is included. A change in lattice constant of 1%, for example, can both change the band offset by 60% and generate a ferroelectric instability. Moreover, when spin-orbit coupling is included, an unusually fine kpoint mesh is needed to converge the phonon frequencies, forces and Fermi energy. This unusual sensitivity to the input parameters in the calculation is of course related to the many interesting properties of PbTe, which is on the boundary between various competing structural (incipient ferroelectricity 20,21) and electronic (superconductivity¹⁰⁻¹² and topological insulator^{22,23}) instabilities. Interestingly, we show in Appendix C that the volume does not significantly affect the computed evolution with doping of the cyclotron masses and the frequencies of quantum oscillations. Therefore, experimental variations in volume, as occur for example with temperature, do not affect our conclusions.

A. Computational details

Our calculations were performed using the PAW implementation^{24,25} of density functional theory within the VASP package²⁶. After carefully comparing structural and electronic properties calculated using the local density approximation (LDA)²⁷, PBE²⁸ and PBEsol²⁹ with available experimental data, we chose the PBEsol exchange-correlation functional as providing the best overall agreement. We used a $20 \times 20 \times 20$ Γ -centered

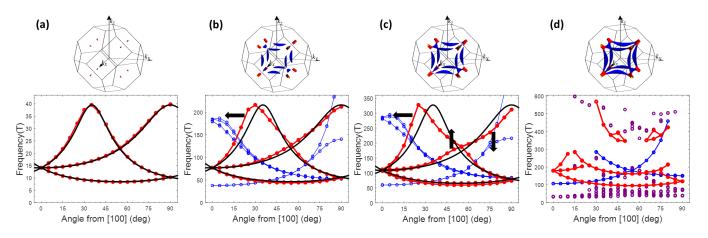


FIG. 2. (Color online) Upper panel: Fermi surface of hole-doped PbTe calculated in this work using the rigid band approximation. Lower panel plots: The corresponding (110)-plane angle evolution of the cross-sectional areas (in frequency units) of the calculated Fermi surface pockets. The four columns correspond to monovalent impurity concentrations of: (a) x = 0.02% $(p_L = 0.27 \times 10^{19} \text{ cm}^{-3} \text{ and } p_{\Sigma} = 0)$; (b) x = 0.81% $(p_L = 3.5 \times 10^{19} \text{ cm}^{-3} \text{ and } p_{\Sigma} = 8.6 \times 10^{19} \text{ cm}^{-3})$; (c) x = 1.56% $(p_L = 6.1 \times 10^{19} \text{ cm}^{-3} \text{ and } p_{\Sigma} = 17.4 \times 10^{19} \text{ cm}^{-3})$; and (d) x = 2.61% $(p_{total} = 36.2 \times 10^{19} \text{ cm}^{-3})$. The frequencies of the L-pockets are shown in red, and compared with those expected in a perfect ellipsoidal model shown as black lines. The evolution of the Σ -pockets is shown in blue. These pockets appear at a dopant concentration of x = 0.11% $(p_L \approx 10^{19} \text{ cm}^{-3})$. In column (d), the Σ and L-pockets have merged, forming a cube-shape Fermi surface; cross-sections that can not be identified separately with Σ or L are shown in purple. We plot frequencies up to 600 T, noting, however, that frequencies up to 8 kT occur, corresponding to the large-square Fermi surface orbits. As described in the main text, our quantum oscillation studies reveal that for carrier densities up to at least $9.4 \times 10^{-19} \text{ cm}^{-3}$ value, the maximum studied in this report, the Fermi surface is found to only comprise L-pockets (shown in red), implying a larger band offset between the L- and Σ -pockets than predicted by these and other DFT calculations.

k-point mesh and to ensure a convergence below 0.1 μ eV for the total energy used a plane-wave energy cutoff of 600 eV and an energy threshold for the self-consistent calculations of 0.1 μ eV. We used valence electron configurations $5d^{10}6s^26p^2$ for lead, $5s^25p^4$ for tellurium, and $2p^63s^1$ for sodium. Spin-orbit coupling was included. The unit cell volume was obtained using a full structural relaxation giving a lattice constant of 6.44 Å(to be compared with the experimental 6.43 Å²⁰ at 15 K). Kohn-Sham band energies were computed on a fine ($140 \times 140 \times 140$) threedimensional grid covering the entire Brillouin zone and used as an input for the SKEAF code³⁰ which allows for extraction of extremal cross-sectional areas of the Fermi surface in different spatial orientations.

B. Rigid-band approximation

First, we computed the Fermi-surface evolution as a function of doping (shown in Fig. 2) by rigidly shifting the Fermi energy in the pure PbTe structure and assuming one hole per dopant. This rigid-band approximation allows very fine samplings of the Brillouin zone, which are necessary to characterize the tiny Fermi surface of hole-doped PbTe at low doping. We discuss its validity here, by comparing with calculations in which a Pb ion is substituted explicitly with a Na ion. Many firstprinciples studies^{31–36} have already been carried out to determine the effect of different dopant atoms on the electronic properties of PbTe, with some of them explicitly assessing the validity of the rigid band approximation in Na-doped PbTe: Takagiwa *et al.*³⁵ confirmed from KKR-CPA calculations that the density of states (DOS) behaves as in a rigid band model, whereas Hoang *et al.*³⁷ and Lee and Mahanti³⁶ showed that a lifting of degeneracy occurs at the top of the valence band with explicit Na doping (at a concentration of 3.125%), with the consequence that the rigid band approximation overestimates the thermopower³⁶. Here we study how sodium impurities affect the band structure of PbTe close to the Fermi energy for the lower concentrations that we use in our experiments ($x \leq 1\%$).

We show here results for a $4 \times 4 \times 4$ supercell of the primitive cell containing 128 atoms ($x \approx 1.6\%$), with one lead ion substituted by sodium. The unit cell volume was kept the same as in pristine PbTe (it would be changed by less than 0.1% by a full structural relaxation). We checked also that our conclusions are qualitatively unchanged for a larger 216 atom supercell ($3 \times 3 \times 3$ of the conventional cubic cell) in which one or two lead ions are substituted by sodium ($x \approx 0.9\%$ or $x \approx 1.6\%$). The *k*-point mesh was accordingly scaled down and spin-orbit coupling was not included because of computational cost; the other computational settings were left unchanged.

Figure 3 (a) shows the partial density of states in the region of the Fermi level from the sodium impurity for $x \approx 1.6\%$. Note the small value on the y axis indicating that the contribution from the Na atom is very small. It

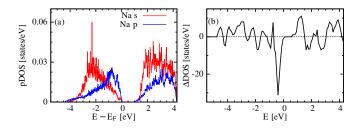


FIG. 3. (Color online) Sodium contribution to the calculated band structure around the Fermi energy for the 128-atom supercell. (a) Sodium projected density of states (pDOS). (b) Difference in the total DOS with and without the impurity, $\Delta DOS = DOS_{with Na} - DOS_{undoped}$. Note the drop in DOS just below the top of the valence band (set to 0 eV), consistent with a lifting in degeneracy of the highest valence bands (see also Fig. 4).

does, however, have an influence on the electronic band structure which can be seen in Fig. 3 (b), where we plot the *difference* in density of states with and without the impurity. Here we see a distinct drop in the DOS (note the higher values on the y axis) just below the top of the valence band (set to 0 eV) due to band shifts caused by the presence of the Na atom; we analyze these next.

In Fig. 4 we compare the calculated electronic band structure with and without the sodium impurity. In Fig. 4 (a) we show both band structures on the same y axis with the zero of energy set to the top of the valence band. We see that the two band structures are close to identical, except for a lifting of the eight-fold degeneracy at the top of the valence band, indicated by black arrows, in the case of the explicit Na doping. A consequence of this shift in one of the valence bands is a shift of the Fermi energy to lower energy relative to its position in the rigid band approximation. We illustrate this in Fig. 4 (b) where we set the zero of energy to be the Fermi energy for each case. In contrast with earlier calculations at a larger doping 36,37 , the lifted band *does* contribute to the Fermi surface and affects the quantitative evolution of Shubnikov-de Haas frequencies with hole density, giving rise to a more complex Fermi surface having L-pockets with different sizes. The folding of wave vectors and states in the supercell makes an estimation of the different ellipsoidal axes difficult. In any case, the amplitude of the quantum oscillations for the "lifted-degenerate" pockets would be weaker. From these considerations we are confident that our rigid-band calculations can be used to make *qualitative* predictions about the evolution of the Fermi surface with Na doping. Quantitative predictions are anyway difficult because of the previously discussed sensitivity on the parameters used for the calculations.

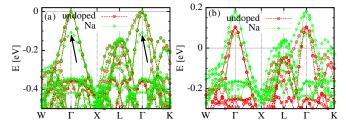


FIG. 4. (Color online) Calculated band structure with and without sodium impurity for the 128-atom supercell ($x \approx 1.6\%$). (a) The zero of energy was set at the top of the valence band for both cases. Note the lifting of the degeneracy of the top valence bands (marked by arrows); apart from this, the bands coincide almost perfectly. (b) The carrier density for both cases was fixed to a concentration corresponding to x = 1.6%. The Fermi energy is moved more into the valence band than expected from the rigid band approximation because of the lifting of degeneracy.

C. Calculated Fermi surface evolution and angle evolution of Shubnikov-de Haas frequencies

Our calculated energy dispersion for PbTe, along the high symmetry directions of the FCC Brillouin zone, is plotted in Fig. 1. As discussed above, we obtain a direct gap at the L-point, followed by a second valence band maximum at the Σ_m -point, 70 meV below the top of the valence band. Figure 2 shows our calculated Fermi surfaces, as well as the (110)-plane angle dependence of the Fermi surface pocket cross-sectional areas, or equivalently, Shubnikov-de Haas (SdH) frequencies (see Appendix A), for four impurity concentrations. The (110)plane is a natural plane to study the angle evolution of the SdH frequencies for this material, given that, in a perfect ellipsoidal scenario, it allows the determination of all the extremal cross-sectional areas of both, L- and Σ -pockets. For low impurity concentrations, the Fermi surface is formed only by L-pockets, which follow the angle dependence expected for a perfect ellipsoidal model. At intermediate concentrations, the Σ -pockets appear, and clear deviations from the perfect ellipsoidal model for L-pockets (and Σ -pockets) are observed. For impurity concentrations above x = 1.8%, Σ - and L-pockets merge together to form the Fermi surface shown in Fig. 2(d). At this point, very high frequency (≈ 8 kT, corresponding to the large-square Fermi surface pieces) and very low frequency features are expected, and a whole new variety of cross-sectional areas coming from different sections of the Fermi surface make the tracking of continuous angle dependence curves more challenging.

For the L-pockets, we observe a progressive evolution to non-ellipsoidicity, characterized by three main features in the angle dependence plots: (i) an increasing splitting in the low frequency branch, indicative of deformations of the L-pockets around the semi-minor axis region; (ii) a shifting to lower values of the angle at which the maximum cross-sectional area (maximum frequency) is

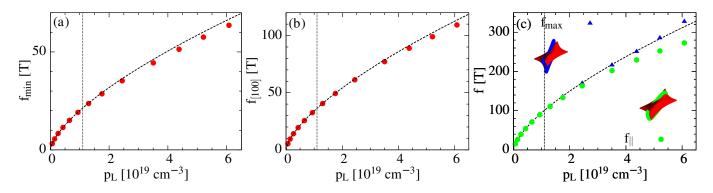


FIG. 5. (Color online) Evolution of three calculated cross-sectional areas (in frequency units) with density of holes in the L-pockets (p_L) . The dashed curve in all the plots shows the functional dependence of $p_L^{2/3}$ expected for a perfect ellipsoidal model. The dotted vertical line indicates the L-pocket hole density above which the Σ -pockets start to be populated. (a) Frequency associated with the L-pockets minimum cross-sectional area, f_{min} ; (b) Frequency associated with the L-pockets' cross-sectional area in the [100] direction, $f_{[100]}$; (c) Frequencies associated with the L-pockets' maximum cross-sectional area. The green circles correspond to the orbits in the longitudinal direction of the L-pocket (f_{\parallel}) – for perfect ellipsoidal L-pockets they would correspond to the largest possible frequencies; the blue triangles correspond to the orbits associated with the largest cross-sectional area f_{max} , which for large concentrations do not correspond anymore to longitudinal orbits on the L-pockets. The inset shows two representative orbits (f_{\parallel} in green and f_{max} in blue) on the distorted L-pocket (shown in red) for a concentration x = 1.56% ($p_L = 6 \times 10^{19} \text{ cm}^{-3}$).

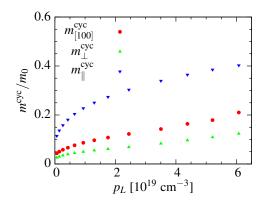


FIG. 6. (Color online) Evolution of calculated cyclotron effective masses (Eq. A5) as a function of density of holes in the L-pocket (p_L) at three high symmetry directions: \parallel or in the longitudinal direction of the L-pocket, in the [100] direction, and \perp or in the transverse direction of the L-pocket (corresponding to a magnetic field oriented along the [111] direction). The variation with p_L provides striking evidence for the non-parabolicity of the bands.

found, indicative of L-pocket deformations around the semi-major axis region, and due to the formation of the tips that will eventually join with the Σ -pockets at high enough dopant concentration; (iii) some distortions of the dispersion branch that goes from the [100] frequency value to the maximum frequency value at 90°, generating a cusp at 90°.

Figure 5 shows our calculation of three extremal crosssectional areas with density of holes in the L-pockets (p_L) computed from the Kohn-Sham band energies. The dashed curves indicate the expected $p_L^{2/3}$ behavior for perfect ellipsoidal pockets. Deviations of the computed cross-sectional areas from the perfect ellipsoidal dependence become noticeable close to hole densities in the L-pockets above which the Σ -pockets start to be populated, which is indicated by the vertical dotted lines in Fig. 5. These deviations are characterized by a shift toward lower frequencies from that expected in the perfect ellipsoidal model. Additionally, Fig. 5(c) highlights the distortions in the L-pockets, which cause the shift in the maximum frequency from 35° (f_{\parallel}) towards smaller angles in the angle-evolution curves shown in Figs. 2(b) and 2(c).

Figure 6 shows our calculated evolution of cyclotron effective masses (Eq. A5) at three high symmetry directions as a function of the carrier content of the L-pockets. A monotonic increase of cyclotron masses with carrier concentration is observed, implying a non-parabolicity of the L-band even at the top of the band. It is interesting to note that although deviations from perfect ellipsoidicity as seen in the calculated angle evolution (Fig. 2(a)) and the calculated SdH frequencies (Fig. 5) are close to zero for the low carrier concentration regime, the variation of the effective masses at the lowest doping levels already points to the non-parabolicity of the highest valence band. Note that this was already taken into account in some transport studies of PbTe to compute its thermoelectric properties^{38,39}.

In summary, our density functional calculations of the evolution of the Fermi surface of PbTe with doping provide some guidelines for identifying signatures of deviations from perfect ellipsoidicity and perfect parabolicity in our quantum oscillation experiments, to be presented in the coming sections. As we mentioned previously, the main signatures in the angular dependence of cross-sectional areas of L-pockets are: (i) An increasing splitting in the low frequency branch, indicative of deformations of the L-pockets around the semi-minor axis region;

(ii) A shifting to lower values of the angle at which the maximum cross-sectional area (maximum frequency) is found, indicative of L-pocket deformations around the semi-major axis region, and due to the formation of the tips that will eventually join with the Σ -pockets at high enough dopant concentration;

(iii) Some distortions of the dispersion branch that goes from the [100] frequency value to the maximum frequency value at 90° , generating a cusp at 90° ;

(iv) A monotonic increase of the cyclotron effective mass of holes as a function of carrier concentration.

Our computational findings (i)-(iii) will be used in the next section in interpreting deviations from perfect ellipsolicity in our experimental data.

Finally, we note that, although we find that doping slightly increases the unit cell volume (see Appendix B - Table AI) our calculations show that our conclusions above are largely unaffected: as shown in Appendix C, even if the band-structure parameters are influenced by volume, the evolution of SdH frequencies and cyclotron masses with doping are almost unaffected.

III. EXPERIMENTAL TECHNIQUES

A. Sample preparation

 $Pb_{1-x}Na_xTe$ single crystals were grown by an unseeded physical vapor transport (VT) method, similar to that described in Ref. 11, by sealing in vacuum polycrystalline pieces of the already doped compound, with (or close to) the desired final stoichiometry. The polycrystalline material was obtained by mixing high purity metallic lead (99.999%, Alfa Aesar), tellurium (99.999+%, Alfa Aesar) and sodium (99.9%,Sigma Aldrich) in the appropriate ratios. The source materials were placed in alumina crucibles, sealed in evacuated quartz tubes, and heated up to 1000 °C, holding this temperature for 7 hours, followed by a rapid quench in water. A subsequent sinter at 700 °C for 48 hours was performed with the material contained in the same evacuated tube⁴⁰. After this process, the material was removed from the crucible, ground into fine powders, and then cold-pressed into a pellet. The pellet was sealed in a quartz tube, with a small argon pressure to prevent mass transport. The pellet was then sintered again at 500 $^{\circ}C$ for 24 hours, and finally it was broken into small pieces to be used in the VT stage. After the VT, mm-size single crystals, with clear cubic facets, were obtained. The final sodium content was estimated through the determination of the carrier concentration via Hall coefficient (p_H) measurements (at T = 1.5 K), assuming one hole per Na dopant. Direct determination of the dopant concentration is challenging for the low Na concentrations studied in this work (< 0.62%) which are below the weight %

resolution of the available electron microprobe analysis tools.

B. Magnetoresistance measurements

High-field magnetoresistance measurements of $Pb_{1-x}Na_xTe$ single crystal samples with different x values between 0 and 0.62% (carrier concentrations up to $p_H = 9.4 \times 10^{19} \text{cm}^{-3}$) were taken at the DC facility of the National High Magnetic Field Laboratory (NHMFL), in Tallahassee, FL, USA, for magnetic fields up to 35 T. $Pb_{1-x}Na_x$ Te single crystals were cleaved in rectangular shapes with faces along the [100] directions. Typical sizes of the resulting crystals were 1 mm in the longest side. Four gold pads were evaporated on one of the faces in order to improve electrical contact with the crystal. Gold wires were attached to each of the pads using silver epoxy, and the other end of each wire was pasted to a glass slide. Twisted pairs coming from the rotator 8-pin dip socket were connected to the glass slide, with special care taken to minimize the loop areas of the wires. Four-point resistance curves for different field orientations and temperatures were taken for plus and minus field sweeps (in order to extract the symmetric component of the magnetoresistance) with temperature and field orientation held constant. In order to vary the sample orientation with respect to the magnetic field, samples were mounted on a stepping-motor driven single-axis rotator, which allows in-situ rotations with resolution of 0.1° . Samples were mounted in the rotator with their (100) faces along different directions with respect to the rotator axis, depending on the desired plane of rotation. Field-sweep data was taken each 5° or 7.5° , going in one direction to prevent rotator backlash problems.

IV. EXPERIMENTAL RESULTS

We divide the results section into two parts: In subsection A we show the angle dependence of the magnetoresistance as the magnetic field is rotated within a high symmetry crystallographic plane, and temperature is held fixed at (1.5 ± 0.2) K. This allows us to obtain information about the topology of the Fermi surface and its evolution with carrier concentration. In subsection B we present measurements of the temperature dependence of the amplitude of oscillations in magnetoresistance along different high symmetry directions, in order to extract information about the effective cyclotron masses, and their evolution with carrier concentration.

A. High-field magnetoresistance measurements

All data presented in this section were taken at a temperature of (1.5 ± 0.2) K. For all the samples mea-

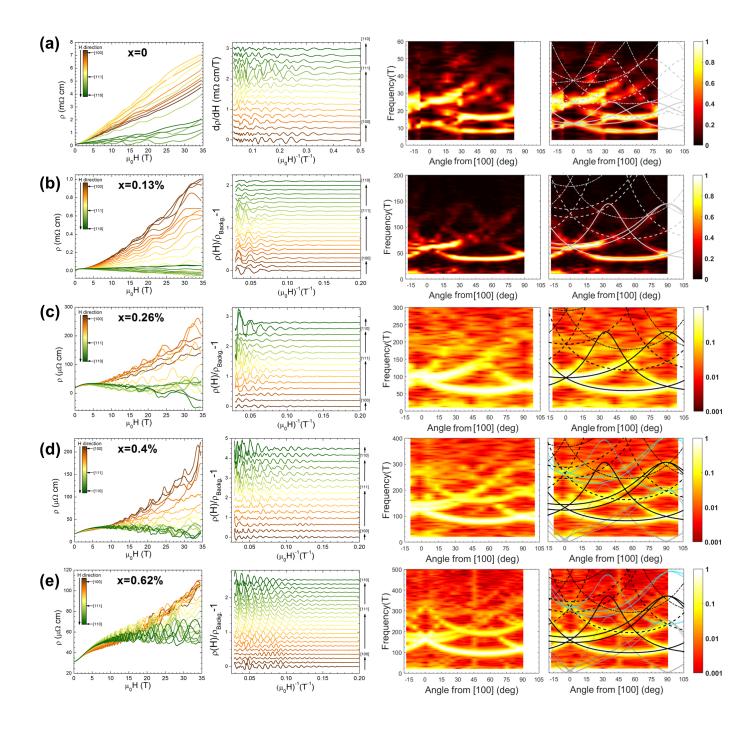


FIG. 7. (Color online) Magnetoresistance measurements for $Pb_{1-x}Na_xTe$ samples of different Na concentrations (row (a) x = 0, row (b) x = 0.13%, row (c) x = 0.26%, row (d) x = 0.4% and row (e) x = 0.62%) as a function of magnetic field rotated along the (110) plane. The first column shows the measured resistivity as a function of applied magnetic field. The second column shows the background-free resistivity, obtained as explained in the main text, as a function of the angle of the magnetic field from the [100] direction (horizontal axis), and the frequency (vertical axis). The last column replots column three, with a comparison to a perfect ellipsoidal model calculation superimposed (solid-lines for fundamental frequencies, and dashed-lines for higher-harmonics). The parameters used for the perfect ellipsoidal model calculation for each set of data are summarized in Table I. For samples with x = 0.13%, 0.4% and 0.62%, small deviations from the (110) plane of rotation are evidenced in the splitting of the angle evolution of the intermediate branch, and they were considered in the perfect ellipsoidal model comparison. For the two highest concentrations, combination frequency terms due to magnetic interaction effects are observed. These are identified in the fourth column plots by the light-blue dotted-lines (sum of fundamental branches) and gray dotted-lines (difference of fundamental branches).

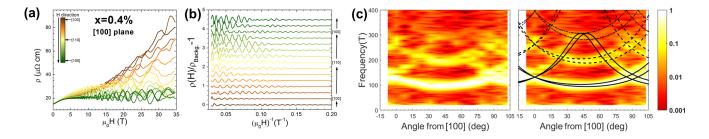


FIG. 8. (Color online) (a) Longitudinal magnetoresistance for a Na-doped PbTe sample with x = 0.4% and Hall number $p_H = 6.3 \times 10^{19} \text{ cm}^{-3}$, for different directions of the applied magnetic field, with respect to the [100] crystalline axis, as the field is rotated in the (100) plane. (b) As in (a), as a function of inverse magnetic field, after eliminating the background, therefore only preserving the oscillatory part. (c) The color scale in both plots represents the amplitude of the Fourier transform of the data shown in (b), as a function of the angle from the [100] direction (horizontal axis), and the frequency (vertical axis). For these plots, the field is rotated in the (100) plane. The right hand side figure replots the figure in the left, but with a perfect ellipsoidal model calculation superimposed on the data, up to the third harmonic (black lines). For the model, the plane of rotation is offset by 5.5° (about the [100] axis). The parameters used for the calculations are the same as those used for the (110) plane of rotation data in Fig. 7(d): $f_{min} = 81.4$ T and $f_{max} = 307$ T.

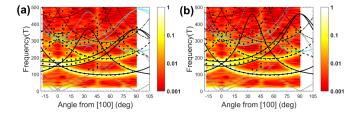


FIG. 9. (Color online) FFT of the background-free resistivity data of Fig. 7(e), as a function of the angle from the [100] direction and the frequency. A perfect ellipsoidal model calculation has been superimposed on the data, up to the third harmonic (black lines). In order to better guide the comparison with the perfect ellipsoidal model, the exact frequencies of the local maxima of the FFT for each angle (labeling only FFT peaks with amplitude 1% or more of the largest peak for each angle) are indicated by black-dots. The parameters used in the perfect ellipsoidal model for each plot are: (a) $f_{min} = 97$ T, $f_{max} = 370$ T; and (b) $f_{min} = 97$ T, $f_{max} = 460$ T. For both plots, an offset of 4° from the (110) plane of rotation (about the [110] axis) is considered, to account for the splitting seen in the middle branch. Additionally, the combination frequency terms are shown in light-blue-dotted lines (sum of fundamental branches) and gray-dotted lines (difference of fundamental branches). None of the fits presented here give a satisfactory description of the data, suggesting deviations from perfect ellipsoidicity.

sured, large Shubnikov-de Haas (SdH) oscillations in magnetoresistance were observed starting at a field of approximately 4T for most samples. The first column of Fig. 7 shows symmetrized measurements of resistivity, ρ , as a function of magnetic field for Pb_{1-x}Na_xTe with (a) x=0 ($p_H = 1.9 \times 10^{18}$ cm⁻³), (b) x=0.13% ($p_H =$ 2.1×10^{19} cm⁻³), (c) x=0.26% ($p_H = 4.1 \times 10^{19}$ cm⁻³), (d) x=0.4% ($p_H = 6.3 \times 10^{19}$ cm⁻³) and (e) x=0.62%($p_H = 9.4 \times 10^{19}$ cm⁻³), for different field orientations in the (110) plane. As mentioned in section II C, the (110) plane is a natural plane to study the angle evolu-

tion of the SdH frequencies for this material, given that, in a perfect ellipsoidal scenario, it allows the determination of all the extremal cross-sectional areas of both L- and Σ -pockets. The second column of Fig. 7 shows the oscillating component of the respective magnetoresistance curves, as a function of inverse field, extracted after the following background elimination procedure: for such low carrier densities, which imply low frequencies of oscillation, the determination of the frequencies and the tracking of their evolution with angle is challenging, given that only a few periods of oscillations are observed for the field range used, and additionally, several artifacts coming from background subtractions have characteristic frequencies that are comparable to the frequencies of interest. In our data analysis, several methods for background subtraction were tested. The method that generated the best resolution in the fast Fourier transform (FFT) for all the Na-doped samples, and that we use here, was a cubic-spline fitting of the non-oscillating component. For the self-doped x=0 sample, which is the sample with the lowest characteristic frequencies (as low as 8 T), the method that allowed the best resolution of the evolution of fundamental frequency branches was the computation of the first derivative.

The evolution with angle of the frequencies of oscillation is shown in the contour plots of the third and fourth columns of Fig. 7. The color scale for these plots represents the amplitude of the FFT of the corresponding curves in the second column, normalized by the maximum value of the FFT at each angle, as a function of the angle from the [100] direction, and frequency. For all samples, the fundamental frequency of the three expected branches of frequency evolution is clearly observed, and for some of the branches, the second and third harmonic can be identified. For the x=0 sample, the second harmonic seems to be stronger in amplitude than the fundamental, for all three branches. This effect is likely associated with the difficulty of resolving low frequency signals.

TABLE I. Fermi surface parameters for Na-doped PbTe, obtained from comparison between our measured data and a perfect ellipsoidal model. p_H is the Hall coefficient obtained though Hall measurements (at T = 1.5 K); f_{\min} and f_{\max} are the transverse and longitudinal cross-sectional areas of the L-pockets, respectively; $K = (f_{\max}/f_{\min})^2$ is the anisotropy of L-pockets (see Appendix D); p_{FS-Vol} is the carrier concentration computed using Luttinger's theorem (see section VA).

x(at.%)	$p_H(\times 10^{19} {\rm cm}^{-3})$	f_{min} (T)	$f_{[100]}$ (T)	f_{max} (T)	K	$p_{FS-Vol} (\times 10^{19} \text{cm}^{-3})$
0	0.19 ± 0.001	8 ± 1	12.5 ± 2	25 ± 2	10 ± 4	0.16 ± 0.02
0.04	0.75 ± 0.01	17 ± 5	34 ± 7	-	-	-
0.13	2.09 ± 0.01	39 ± 4	63 ± 5	145 ± 7	14 ± 3	2.1 ± 0.2
0.26	4.1 ± 0.06	60 ± 8	97 ± 10	230 ± 7	15 ± 4	4.0 ± 0.3
0.4	6.3 ± 0.6	81 ± 4	132 ± 13	307 ± 6	14 ± 2	6.3 ± 0.2
0.62	9.4 ± 0.6	97 ± 12	157.5 ± 16	370 ± 90	15 ± 8	8.3 ± 2.1

For all samples, the branch that lies in the low frequency region for all angles contributes the dominant frequency in the magnetoresistance, which is associated with its higher mobility with respect to the other two branches. For the higher concentration samples, the high frequency contributions are weaker, and a logarithmic scale in the contour plots is used in order to highlight their angle evolution. In order to determine the characteristic frequencies of oscillation, and the possible deviations of the Fermi surface from a perfect ellipsoidal model, a comparison of these plots with the frequency evolution for a Fermi surface containing eight half-ellipsoids at the L points (perfect ellipsoidal model) is shown in the fourth column plots of Fig. 7. The fundamental frequencies, as well as the second and third harmonics are shown for each sample. The splitting seen in the intermediate frequency branch for most of the samples can be successfully accounted for by a small offset in the plane of rotation. For the x=0 sample, an offset of 12° about the [001] axis was considered in the perfect ellipsoidal model. For samples with x = 0.13%, the offset is 3° about the [110] axis; and for x = 0.4% and 0.62%, the offset is 4° about the [110] axis.

The parameters of minimum and maximum crosssectional areas $(f_{min} \text{ and } f_{max})$ used in the perfect ellipsoidal model comparison for each sample are summarized in Table I. The minimum cross-sectional area of the L-pockets, associated with f_{min} , can be determined very accurately from the value of the fundamental frequency of oscillation at 55° from the [100] direction in the (110) plane, which is clearly observed for all the samples measured. Additionally, the maximum cross-sectional area of the L-pockets, associated with f_{max} , can be directly observed in the FFT plots of samples with Na concentration up to 0.4%. Also, up to this concentration, the matching between the angle evolution of the frequencies of oscillation with that expected for a perfect ellipsoidal model is satisfactory. Nevertheless, for this last concentration, the maximum frequency of the ellipsoids is resolvable close to 90° from [100], but becomes blurred close to 35° . Therefore, although the value of the maximum frequency can be determined from the 90° area, possible deviations from ellipsoidal model that could be identified around 35° cannot be resolved. However, given the round shape of the upper-branch around 90°, we can say that features associated with possible departures from the ellipsoidal model are not observed (see Fig. 2(c)). This last statement is confirmed by magnetoresistance measurements in an additional sample of the same batch as the field is rotated along the (100) plane, as shown in Fig. 8. The comparison of the FFT angle evolution and the perfect ellipsoidal model, using the same extremal cross-sectional area parameters as for the measurements with field along the (110) plane, confirms the matching of the data with the perfect ellipsoidal model for samples of this Na composition (x=0.4%). For the highest Na concentration sample measured, x=0.62%, possible deviations from perfect ellipsoidicity are observed, and will be discussed later in this section.

As can be seen in the third and fourth columns of Figs. 7(d) and (e), additional features in the angle dependence plots occur for the two highest Na-doped samples. Nevertheless, all of these features can be identified as the sum and difference of the fundamental frequencies of the L-pockets, as can be observed in the light-blue and gray curves in the fourth column plots of Figs. 7(d) and 7(e). The presence of such combination frequencies can be attributed to magnetic interaction effects, expected when the amplitude of the oscillating component of the magnetization, \tilde{M} , is comparable to H^2/f , in such a way that the total magnetic field $\vec{B} = \vec{H} + 4\pi \vec{M}$, and not just \vec{H} , needs to be considered in the Lifshitz-Kosevich (LK) formalism of quantum oscillations⁴¹ (see Appendix A).

As was suggested above, the sample with the highest Na concentration studied in this work, x = 0.62%, shows possible indications of deviations from perfect ellipsoidicity. For this sample the high frequency components of the oscillations are blurred, and the evolution of the different branches can be observed only up to 400 T. As we mentioned previously, the determination of f_{min} for all samples has a very low uncertainty, particularly for this sample, given that we can clearly observe up to the thirdharmonic of the lower branch (see Fig. 7(e)). Fixing this value to $f_{min} = 97$ T, Fig. 9 shows a comparison between the angle evolution of the frequencies of oscillation for this sample, and a perfect ellipsoidal model using two different values of f_{max} . In order to better guide the comparison, both plots in this figure show the exact frequency positions of the maxima of the FFT peaks for all angles (in black-filled circles). Around the angle of 90° we observe some weight in the FFT (vellow color) around 350-370 T, which we could interpret as an indication of the value of f_{max} . This value is the one used in the perfect ellipsoidal model in Fig. 9(a) (as well as Fig. 7(e)). In this figure, we can see that the matching between the data and the perfect ellipsoidal model is not satisfactory. especially close to the 0° area of the plot. Interestingly, the 90° -370 T area overlaps with the region at which the third harmonic of the lower branch passes. This could indicate that the weight observed at this region belongs to this third harmonic, and not to f_{max} . Figure 9(b) shows a comparison between the data and a perfect ellipsoidal model using the same $f_{min} = 97$ T, but now using a larger value of $f_{max} = 460$ T. These values provide a better matching between the data and a perfect ellipsoidal model for the region of 0° . However, the combination frequency terms, due to magnetic-interaction effects, suggest that this fit is not satisfactory, as the evolution of the combination frequency data points around 60°-350 T seems to be less steep, being better matched by the fit using $f_{max} = 370$ T, as shown in Fig. 9(a). The lack of a satisfactory perfect ellipsoidal model to describe the data can be interpreted as deviations from perfect ellipsoidicity of the L-pockets for this Na concentration. The mismatch of the data and the ellipsoidal model is observed in the intermediate branch, which is consistent with the guidelines given by the DFT calculations.

For all the measured samples, all features observed in the angle evolution of the frequencies of oscillations come from the L-pockets. Furthermore, the carrier concentration calculated from Luttinger's theorem and the volume in k-space of the L-pockets (obtained through the comparison of the FFT evolution and the perfect ellipsoidal model), p_{FS-Vol} , matches perfectly (within the error bars) the Hall number (equivalent to the carrier concentration for a single band compound) for all Nadoped samples up to x = 0.4%, as shown in Table I: the L band contributes solely to conduction up to this Na concentration. Moreover, the small mismatch between the L-pocket Luttinger volume and the Hall number for the highest Na concentration sample, x = 0.62% presumably comes from deviations from perfect ellipsoidicity, as previously discussed.

B. Temperature dependence of Quantum Oscillations

In order to determine the evolution of effective cyclotron masses of holes in Na-doped PbTe with carrier concentration, we measured the temperature dependence of the oscillation amplitude for samples of different Na concentrations, with the field oriented along or close to high symmetry crystallographic directions. To accurately determine the cyclotron effective masses for such a low carrier-density material, we simultaneously fitted all

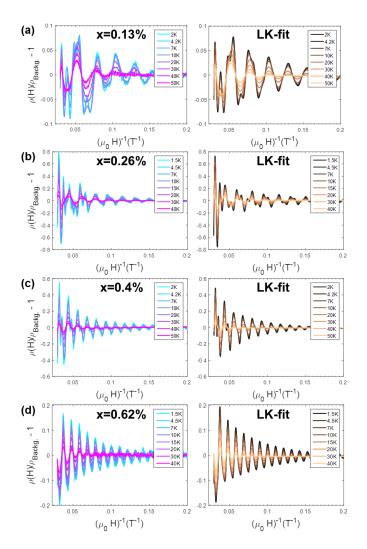


FIG. 10. (Color online) Temperature dependence of the amplitude of the oscillating component of magnetoresistance for $Pb_{1-x}Na_xTe$ samples, with magnetic field along the [111] direction (55° from the [100] direction, in the (110) plane). The left-column plots show the background-free data at different temperatures. The right-column plots show the fits of the data to the LK-formula in Eq. 1, using the four most dominant frequencies observed in the FFT of the lowest temperature curve. From this fit, the values of cyclotron effective mass and Dingle temperature, for each frequency term, are obtained. The values obtained for the transverse cyclotron mass and Dingle temperature are summarized in Table II.

magnetoresistance curves to the Lifshitz-Kosevich (LK) formula (in SI units)⁴¹:

$$\frac{\rho(H) - \rho_0}{\rho_0} = \sum_i C_i \left\{ \exp\left(\frac{-14.7(m_i^{cyc}/m_e)\Theta_{D,i})}{H}\right) \right\} \\ \times \left\{ \frac{T/H}{\sinh\left(14.7(m_i^{cyc}/m_e)T/H\right)} \right\} \\ \times \cos\left[2\pi \frac{f_i}{H} + \phi_i\right]$$
(1)

TABLE II. Cyclotron effective masses for $Pb_{1-x}Na_xTe$ samples along different high symmetry directions. These parameters were obtained through fitting of the curves in Figs. 10, 11 and A3 to the LK-formula in Eq. 1.

x(at.%)	$p_H(\times 10^{19} cm^{-3})$	$\Theta_{D,\perp}$ (K)	m_{\perp}^{cyc}/m_e	$m_{[100]}^{cyc}/m_e$	m_{\parallel}^{cyc}/m_e
0.04	0.75 ± 0.007	-	-	0.098 ± 0.001	-
0.13	2.09 ± 0.006	9 ± 4	0.068 ± 0.007	0.085 ± 0.001	-
0.26	4.1 ± 0.06	10 ± 3	0.089 ± 0.002	0.15 ± 0.01	0.29 ± 0.04
0.4	6.3 ± 0.6	9.9 ± 0.2	0.14 ± 0.03	0.172 ± 0.004	-
0.62	9.4 ± 0.6	9.5 ± 0.8	0.13 ± 0.02	0.225 ± 0.006	-

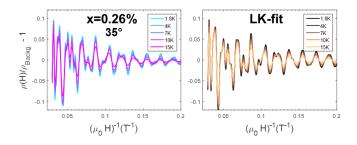


FIG. 11. (Color online) Temperature dependence of the amplitude of the oscillating component of magnetoresistance for a $Pb_{1-x}Na_xTe$ sample with x = 0.24%, and magnetic field oriented close to 35° from the [100] direction, along the (110) plane. For this orientation, the cross-sectional area of two of eight L-pockets corresponds to the maximum cross-sectional area of the ellipsoids. The left-column plot shows the background-free data at different temperatures. The right-column plot shows the fit of the data to the LK-formula in Eq. 1, using the five most dominant frequencies observed in the FFT of the lowest temperature curve. From this fit, the values of cyclotron effective mass and Dingle temperature, for each frequency term, are obtained.

where the sum is over each frequency observed in the data, and for which a separate cyclotron effective mass, m_i^{cyc}/m_e , and Dingle temperature, $\Theta_{D,i}$, can be obtained. For low frequency oscillations, the number of periods observed in the given field range is limited, resulting in FFTs with amplitudes highly dependent on windowing effects, variations in field range or variations in signal sampling. In contrast to the fitting of the FFT amplitudes to the LK formula – the method widely used for the determination of effective masses of higher carrier concentration metals – the values of effective masses obtained through a direct fitting of the LK formula are robust to such variations.

Figure 10 shows the temperature dependence of the oscillating component of magnetoresistance for $Pb_{1-x}Na_xTe$ samples of different Na concentrations, for field oriented along the [111] direction, providing direct access to the transverse cyclotron effective mass, m_{\perp}^{cyc} , which is associated with the minimum cross-sectional area of the L-pockets. Least-squares fits to Eq. 1, including up to the fourth strongest frequency component, for each Na doping, and for a field range of 5 T to 34 T, are shown in the right-column plots of this figure. The cyclotron masses and Dingle temperatures obtained for the fundamental frequency, i.e., m_{\perp}^{cyc} and $\Theta_{D,\perp}$, as a function of carrier concentration, are summarized in Table II, and plotted in Figs. 16 and 17, in the discussion section.

Additionally, Fig. 11 shows magnetoresistance curves at different temperatures for a sample with Na concentration of 0.26%, with the magnetic field oriented close to 35° from the [100] direction in the (110) plane. For such field orientation, one of the Fermi surface cross-sectional areas corresponds to the maximum cross-sectional area of the ellipsoids (in a perfect ellipsoidal model), which is associated with the longitudinal cyclotron mass, $m_{||}^{cyc}$. The value obtained for this mass is presented in Table II.

From our measurements, we can also obtain cyclotron masses along intermediate directions; these are presented in Fig. 15 of the discussion section.

V. DISCUSSION

A. Fermi surface topology

Having presented the data and the analysis performed to obtain the various Fermi surface parameters for different Na-doping levels, we now summarize them and present their evolution as a function of depth in the valence band. The parameters obtained in the previous section are summarized in Table I, where we also include data from an additional Na composition (x = 0.04%) for which measurements in a more limited field range (up to 14 T) were taken.

Figure 12 shows the L-pockets' Luttinger volume as a function of Hall number for the Na-doped PbTe samples studied, plus self-doped (by Pb vacancies) samples measured in previous SdH studies by other groups^{14,15}. For a single-parabolic-band model, these two quantities are expected to exactly match with each other, and to lie on the dashed line shown in the figure. This is indeed the case for all the samples studied, including the self-doped ones. The deviations seen for the largest Na doping can be attributed to deviations from perfect ellipsoidicity of the pockets, as discussed in previous sections. The matching between the L-pockets' Luttinger volumes and Hall numbers implies that PbTe, up to a carrier concentration of $p_H = (9.4 \pm 0.6) \times 10^{19} \text{ cm}^{-3}$, is **single band**, that is, all

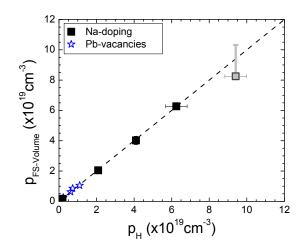


FIG. 12. (Color online) Carrier concentration calculated from Luttinger's theorem and the volume of the L-pockets extracted from the comparison between the data and a perfect ellipsoidal model, as a function of the Hall number, for Nadoped PbTe (black squares), and obtained using the ellipsoid parameters from previous studies in Refs. 14 and 15 (blue stars). The dashed line shows the expected behavior for a single-parabolic band, for which the carrier density enclosed by the Fermi surface, as determined through Luttinger's theorem, matches the carrier density measured using the Hall effect. All the measured samples lie on this line, and the deviations seen for the highest Na doping (gray square) are attributed to deviations from perfect ellipsoidicity.

the carriers contributing to conduction belong to the L band. This result implies that the band offset between the L and Σ valence band maxima is underestimated in our DFT calculations, as well as all previously published band-structure calculations^{8,13,33,34,42–46}, which predict the appearance of the Σ band at a hole concentration of the order of $p \approx 1 \times 10^{19} \text{ cm}^{-3}$.

The evolution of the three high symmetry L-pocket cross-sectional areas, in frequency units (f_{min}, f_{max}) and $f_{[100]}$, with Hall number is plotted in Fig. 13. For a perfect ellipsoidal model, all the cross-sectional areas are expected to scale with carrier concentration as $p_H^{2/3}$. This is in fact the functional form followed by most crosssectional areas in Fig. 13, as shown by the dashed line. The last Na-doped sample deviates from this line, confirming the departure from perfect ellipsoidicity of the pockets for this high carrier concentration. However, for carrier concentrations below $p_H = 6.3 \times 10^{19} \text{ cm}^{-3}$, we can conclude that the L-pockets are well described by a perfect ellipsoidal model, within the experimental resolution. For the highest Na concentration studied, the deviation from the perfect ellipsoidal behavior follows the expected trend predicted by our DFT calculations, as presented in Fig. 5.

Additionally, the anisotropy of the L-pockets, $K = (f_{max}/f_{min})^2$, is approximately constant with carrier concentration ($K = 14.3 \pm 0.4$), for the range of carrier

concentrations of interest, as shown in Fig. 14. The observation of a constant anisotropy of the L-pockets with carrier concentration confirms previous results by Burke et al.¹⁵ for p-type self doped PbTe with carrier concentrations below $1 \times 10^{19} \text{ cm}^{-3}$ (shown as blue stars in Fig. 14), and contrasts the results by Cuff et al.⁴⁷ in self-doped samples with carrier concentrations up to $3 \times 10^{18} \text{cm}^{-3}$. in which a decrease in K with increasing carrier concentration is observed. The K values reported by Burke et al. are slightly less than the average value of 14.3 ± 0.4 found in this work. However, as discussed previously, an accurate estimation of the Fermi surface parameters for the low carrier concentration regime is challenging given the few periods of oscillation observed in a limited field range. This could be the reason for the lower Kvalue obtained for the x = 0 sample measured in this work. A constant value of K with carrier concentration is expected in a perfect parabolic band model, in which the L-pocket anisotropy is equivalent to the band mass anisotropy, $K = m_{\parallel}/m_{\perp}$, where m_{\parallel} is the effective band mass along the ellipsoidal L-pocket semi-major axis (longitudinal band mass), and m_{\perp} is the effective band mass along the ellipsoidal L-pocket semi-minor axis (transverse band mass) (in terms of the cyclotron effective masses, $K = (m_{\parallel}^{cyc'}/m_{\perp}^{cyc})^2$, as shown in Appendix D). However, a constant K value can also be obtained for specific models with dispersion relations in which corrections for nonparabolicity of the band are considered, as we will present in the next section.

B. Effective cyclotron masses and relaxation time

As we presented in section IVB, effective cyclotron masses along different high symmetry directions were obtained through direct fitting of the curves shown in Figs. 10, 11 and A3 to the LK-formula in Eq. 1. For all the Na compositions studied, the cyclotron masses along the transverse direction, m_{\perp}^{cyc} , and [100] direction, $m_{[100]}^{cyc}$, were determined through this method. Additionally, for samples with a Na concentration of x = 0.26%, the lon-gitudinal cyclotron mass, $m_{||}^{cyc}$, was also found. Supplementary to these highly symmetric masses, others along less symmetric directions of the ellipsoid can be found from the different frequency terms in the measurements. Figure 15 shows the cyclotron effective masses found for all frequency terms taken into account in the LK fits of the x = 0.26% sample (Figs. 10(b), 11 and A3(c)), as a function of the angle from the L-pocket longitudinal direction. The corresponding angle for the mass of each frequency term, with respect to the longitudinal direction of the ellipsoids, was found by identifying each frequency in the angle dependence curves, such as that presented in Fig. 7(c). Figure 15 also shows the expected angular dependence of the cyclotron effective mass (fundamental and higher harmonics) in a perfect ellipsoidal model (for more details, see Appendix D), using the average K value from Fig. 14 ($K = 14.3 \pm 0.4$, which

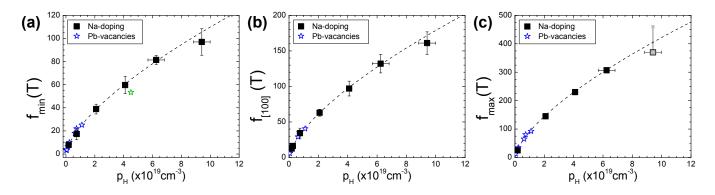


FIG. 13. (Color online) Evolution of the characteristic frequencies of the L-pockets with Hall number, for Na doping, as determined from this study, and for self-doped samples from the works in Refs. 14 and 15: (a) Frequency associated with the L-pockets' minimum cross-sectional area, f_{min} , (b) Frequency associated with the L-pockets' cross-sectional area in the [100] direction, $f_{[100]}$, and (c) Frequency associated with the L-pockets' maximum cross-sectional area, f_{max} . The blue-star symbols are data points obtained by previous quantum oscillation studies from other authors^{14,15}, in self-doped PbTe with different levels of Pb vacancies (the last star in f_{min} , in green, was obtained by Na doping). The f_{max} data point for the highest Na concentration is represented by a gray square, in order to emphasize that deviations from perfect ellipsoidicity seen in this sample result in a less accurate determination of f_{max} . The dashed line in all the plots is the functional dependence of $p_H^{2/3}$ expected for a perfect ellipsoidal model with fixed anisotropy.

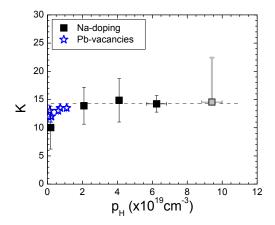


FIG. 14. Anisotropy parameter of the L-pockets, $K = (f_{max}/f_{min})^2$, extracted from the data, as a function of the Hall number for Na-doped samples, as determined from this study (black squares, and gray square for the highest Na composition), and for self-doped samples from the works in Refs. 14 and 15 (blue-stars). The horizontal gray-line shows the average value of $K = 14.3 \pm 0.4$ for this range of concentrations.

gives $m_{\parallel}^{cyc}/m_{\perp}^{cyc} = \sqrt{K} = 3.78 \pm 0.05$). Most data points lie on this curve, confirming the good agreement of the topology of the Fermi surface with the perfect ellipsoidal model for this Na concentration.

In spite of the good agreement of the anisotropy of the cyclotron effective mass with the perfect ellipsoidal model, intriguingly, the masses are not constant throughout the band: Fig. 16 shows the evolution of the longitudinal, transverse and [100] direction cyclotron effective masses with carrier concentration. All of them show a monotonic increase with increasing carrier concentration, consistent with the predictions of the DFT bandstructure calculations presented in section II C. Previous SdH measurements in p-type self-doped PbTe by Burke et al.^{14,15} ($p_H < 1 \times 10^{19}$ cm⁻³), and by Cuff et al.⁴⁷ ($p_H < 6 \times 10^{18}$ cm⁻³), found a similar tendency for the transverse cyclotron mass. The observation of a varying effective mass with carrier concentration implies deviations from perfect parabolicity, starting from the top of the band.

A Kane model dispersion relation has been proposed before to describe the valence band of $PbTe^{33,48-51}$. In this model the non-parabolicity of the band is introduced as $E \longrightarrow \gamma(E) = E(1 + E/E_q)$ in the dispersion relation, where E_g is the band gap. For such a model, the longitudinal and transverse effective masses depend on energy in the same way⁴⁹, implying that, although the effective masses evolve as the Fermi energy is changed, the band anisotropy parameter, $K = (A_{\parallel}/A_{\perp})^2 = (m_{\parallel}^{cyc}/m_{\perp}^{cyc})^2$, is constant. Additionally, in this model, the constant energy surfaces for any Fermi energy are ellipsoids of revolution⁴⁹, which is consistent with our observations for carrier concentrations up to $p = 6.3 \times 10^{19} \text{cm}^{-3}$. The Kane model has been successful at describing the band structure near the gap of small band-gap semiconductors, for which the relevant Fermi energies are smaller than or of the same order as the band gap^{52} . Our experimental results are in line with the predictions of the Kane model, ruling out other proposed models such as the Cohen $model^{49,53,54}$, at least for the low temperature regime.

Additional to the cyclotron effective masses, we have found the Dingle temperature in the transverse direction,

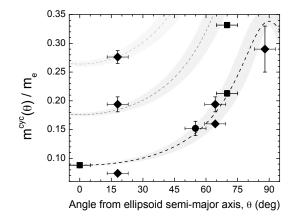


FIG. 15. (Color online) Cyclotron effective mass, m^{cyc} , along different directions with respect to the (L-pocket) ellipsoid semi-major axis, for a $Pb_{1-x}Na_xTe$ sample with x = 0.24%. The data points were obtained through fits to the LK-formula of the oscillating components of magnetoresistance along three different crystallographic directions: [111] (Fig. 10(b)), (100) (Fig. A3(d)), and 35° from [100] in the (110) plane (Fig. 11). The dashed-lines represent the angle dependence of the cyclotron mass (fundamental and higher harmonics) for a perfect parabolic dispersion and perfect ellipsoidal model, as presented in Eq. D7, and using an anisotropy parameter $K = 14.3 \pm 0.4$ (which implies $m_{\parallel}^{cyc}/m_{\perp}^{cyc} = 3.78 \pm 0.05$). The shadowed region around the dashed lines represents the error bar in $m_{\perp}^{cyc}(\theta)$ estimated from propagation of errors in K, θ and m_{\perp}^{cyc} .

 $\Theta_{D,\perp}$, through a fitting of the data to the LK-formula, as presented in section IV B. In contrast to the cyclotron mass, finding this quantity along directions other than the transverse direction of the L-pocket ellipses is challenging, given that the oscillatory part of magnetoresistance is dominated by the lowest frequency component. For this dominating part of the signal, the exponential damping in 1/H is the only one strong enough to result in a Dingle temperature as a strong fitting parameter. Figure 17 shows the Dingle temperature associated with the transverse direction, $\Theta_{D,\perp}$, as a function of carrier concentration. This quantity is constant for the range of concentrations studied, with an average value of $\Theta_{D,\perp} = (9.7 \pm 0.4)$ K. This average value of $\Theta_{D,\perp}$ results in a value of the carrier relaxation time along the transverse direction of $\tau_{\perp} = \hbar/2\pi k_B \Theta_{D,\perp} = (0.125 \pm 0.005)$ ps. It is interesting to note that although the RRR value for $Pb_{1-x}Na_xTe$ decreases by approximately 20 times from undoped PbTe to the highest Na-doping studied, suggesting a considerable increase of scattering effects, the transverse relaxation time found in this work is constant with carrier concentration. However, as suggested by the progressive decrease of the Fourier intensity of the higher frequency components as doping is increased, as can be observed in Fig. 7, the enhanced scattering could be reflected in a significant *decrease* of the longitudinal re-

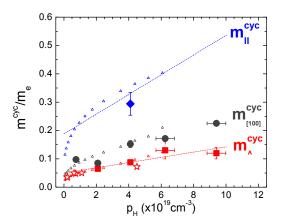


FIG. 16. (Color online) Effective cyclotron mass, m^{cyc} , along three high symmetry directions for $Pb_{1-x}Na_xTe$ samples, as a function of the Hall number. Cyclotron effective masses were determined through fitting the curves in Figs. 10, 11 and A3 to the LK-formula in equation 1. m_{\perp}^{cyc} is the cyclotron mass in the transverse direction of the L-pocket ellipsoid, or [111] direction (red-solid-squares); $m_{[100]}^{cyc}$ is the cyclotron mass in the [100] direction of the crystal lattice (gray-solid-circles); and m_{\parallel}^{cyc} is the cyclotron mass in the longitudinal direction of the L-pocket ellipsoid (blue-solid-diamond). The red-dashed line represents a guide to the eye for the trend observed in the longitudinal cyclotron mass. The blue-dashed line is the trend expected for the longitudinal cyclotron mass given the anisotropy parameter of $m_{\perp}^{cyc}/m_{\perp}^{cyc} = \sqrt{K} = 3.78$. The small open-triangles show the L-pocket effective cyclotron masses determined through our DFT calculations, as shown in Fig. 6. The agreement between the calculated masses and the experimental values for the transverse and [111] direction is outstanding.

laxation time. Unfortunately, a reliable determination of the longitudinal Dingle temperature, resulting in a longitudinal relaxation time, was not possible.

VI. SUMMARY AND CONCLUSIONS

In summary, we have presented a computational and experimental study of the low-temperature (1.5 K to 60 K) topology and properties of the Fermi surface of $Pb_{1-x}Na_xTe$, and its evolution with carrier concentration, for Na dopings up to x=0.62%. We have found that:

(i) Although the band offset is underestimated by the DFT calculations, all the qualitative features of the evolution of the Fermi surface topology and effective mass are correctly predicted by our calculations. The underestimation of the band offset is related to the high sensitivity of the resulting band structure to variations of parameters in the calculation, such as lattice spacing or spin-orbit coupling. This fact is presumably related to the fact that PbTe is on the boundary between vari-

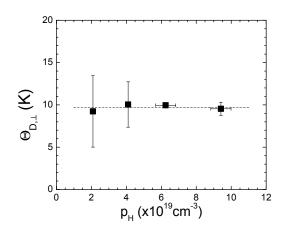


FIG. 17. (Color online) Dingle temperature in the transverse direction, $\Theta_{D,\perp}$, obtained through fitting of the curves in Fig. 10 to the LK formula in Eq. 1, as a function of carrier concentration p_H . We find that the Dingle temperature is independent of carrier concentration, with a value of $\Theta_{D,\perp} = (9.7 \pm 0.4)$ K, indicated by the dashed-gray line. This value of $\Theta_{D,\perp}$ results in a value of $\tau = (0.125 \pm 0.005)$ ps for the carrier relaxation time along the transverse direction.

ous competing structural (incipient ferroelectricity^{20,21}) and electronic (superconductivity¹⁰⁻¹² and topological insulator^{22,23}) instabilities.

(ii) Up to a carrier concentration of $p = 9.4 \times 10^{19} \text{ cm}^{-3}$ (x = 0.62% - maximum studied) the Fermi surface of Pb_{1-x}Na_xTe is formed solely by eight half ellipsoids at the L-points. The Σ -pockets predicted to contribute at such high carrier concentrations in our calculation and those of other groups^{13,42,55–57}, are not observed. Additionally, the measured Hall number and the Luttinger volume of the L-pockets calculated from our quantum oscillation measurements match exactly, indicating that this is the only set of pockets that contribute to conduction in this compound at low temperatures.

(iii) The topology of the Fermi surface, formed by eight half pockets at the L-points, is well described by a per15

fect ellipsoidal model for carrier concentrations up to $p = 6.3 \times 10^{19} \text{cm}^{-3}$ (x = 0.4%). Deviations from perfect ellipsoidicity were resolved for the highest carrier concentration studied, $p = 9.4 \times 10^{19} \text{cm}^{-3}$ (x = 0.62%).

(iv) The anisotropy of the L-pockets is constant for the range of concentrations studied, and has an average value of $K = 14.3 \pm 0.4$.

(v) The anisotropy of the cyclotron effective mass of the L-pockets follows the angular dependence expected in a perfect ellipsoidal model.

(vi) The effective cyclotron masses along all high symmetry directions increase monotonically with increasing carrier concentration, implying deviations from perfect parabolicity of the band. The observation of constant geometric and mass anisotropy with carrier concentration, but an increasing effective mass, is consistent with a Kane model of non-parabolic dispersion relation for the valence band of PbTe.

Our experimental determination of the lowtemperature Fermi surface and band structure parameters of PbTe is an important piece of information which needs to be considered in models that aim at explaining the evolution of a variety of electronic properties at high doping levels in PbTe, including superconductivity and thermoelectric properties.

ACKNOWLEDGMENTS

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APPENDIX

Appendix A: Quantum oscillations formalism

In this section we briefly outline the concepts needed to understand quantum oscillation experiments in metals. For a detailed treatment see the excellent book by Shoenberg⁴¹. It is well known that in a magnetic field H the allowed electronic states lie on quantized tubes in k-space (Landau tubes). The tube quantization is described by the Onsager equation

$$a(E_{n,k_H},k_H) = \left(n + \frac{1}{2}\right) 2\pi e H/\hbar c \quad , \qquad (A1)$$

where a is the cross-sectional area of the Landau tube in a plane perpendicular to H, and n is an integer. As a consequence, an oscillatory behavior with the inverse magnetic field 1/H can be observed in, for example, the magnetization – the de Haas-van Alphen effect – or the resistance – the Shubnikov-de Haas effect. The period of such oscillations, $\Delta_{1/H}$, is given by

$$\Delta_{1/H} = 2\pi e / (\hbar c A) \quad , \tag{A2}$$

A being an *extremal* cross-sectional area of the Fermi surface in a plane perpendicular to H. One can also define a frequency for these oscillations as

$$f = 1/\Delta_{1/H} = (c\hbar/2\pi e)A$$
 . (A3)

By determining the oscillations in, e.g., the resistivity for varying orientations of the magnetic field one can eventually reconstruct the Fermi surface.

In the semi-classical picture the electrons move along (open and closed) orbits on the Fermi surface in a plane perpendicular to H. The time taken to traverse a closed (cyclotron) orbit is given by

$$t_c = \frac{2\pi}{\omega_c} = \frac{\hbar^2 c}{eH} \frac{\partial a}{\partial E} \quad , \tag{A4}$$

where one can rewrite the cyclotron frequency ω_c in terms of a cyclotron mass

$$m^{\rm cyc} = \frac{\hbar^2}{2\pi} \frac{\partial a}{\partial E} \,. \tag{A5}$$

For a free-electron gas the cyclotron mass is equal to the electron mass. Experimentally the cyclotron masses are extracted using the Lifshitz-Kosevich (LK) formula (in SI units)

$$\frac{\rho(H) - \rho_0}{\rho_0} = \sum_i C_i \left\{ \exp\left(\frac{-14.7(m_i^{cyc}/m_0)\Theta_{D,i})}{H}\right) \right\} \\ \times \left\{ \frac{T/H}{\sinh\left(14.7(m_i^{cyc}/m_0)T/H\right)} \right\} \\ \times \cos\left[2\pi \frac{f_i}{H} + \phi_i\right]$$
(A6)

as presented in Eq. 1.

Appendix B: Temperature and Na-composition dependence of the lattice constant

In this section we present an experimental determination of the cubic lattice parameter of $Pb_{1-x}Na_xTe$ samples with different Na content, and its temperature dependence. This determination will be necessary to study the sensitivity of the DFT band-structure calculations to realistic variations in lattice constant, which we present in the next section.

The peak positions of several diffraction peaks with high 2θ values were determined for different temperatures (from 300K down to 80K), using the 2D detector of a commercial Bruker-D8-Venture single crystal X-ray diffractometer. In order to minimize systematic errors. the lattice parameters at each temperature were determined through a linear fit of the calculated lattice spacing for each peak $(a = d_{hkl}\sqrt{h^2 + k^2 + l^2})$ vs. 2θ , and the extrapolation of this fit to $2\theta = 180^{\circ}$. These measurements were done for two Na-doped PbTe samples with Na concentrations of x = 0.26% and 0.62%. The temperature dependence of the lattice parameter of the measured samples, as well as data by Bozin *et al.*²⁰ for undoped PbTe, are shown in Figure A1. Below 150K, the data for x = 0.26% exhibit a greater scatter than those for x = 0.62%, reflecting poorer experimental conditions for that measurement. However, the overall trend of the temperature dependence for both compositions is similar. In order to obtain a sensible extrapolation of our data down to zero-temperature, Bozin's data for un-

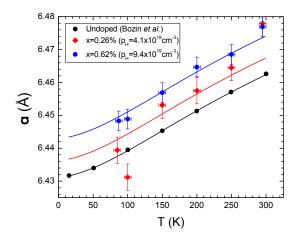


FIG. A1. (Color online) Lattice parameter of the cubic unit cell of $Pb_{1-x}Na_xTe$ samples with different Na content, as a function of temperature. Filled symbols represent the experimentally determined values, and the solid lines represent a fit to a low order polynomial, as explained in the text, from which the zero-temperature lattice parameter can be extrapolated.

TABLE AI. Zero-temperature extrapolated lattice parameter $(a_{T=0K})$ of $Pb_{1-x}Na_x$ Te samples with different Na content. This extrapolation was done through a low-order polynomial fit of the temperature dependence of the lattice parameters, as explained in the text.

x (Na at.%)	$p_H(\times 10^{19} {\rm cm}^{-3})$	$a_{T=0K}$ [Å]
0	_	6.4311(1)
0.26	4.1 ± 0.06	6.436(3)
0.62	9.4 ± 0.6	6.4429(7)

doped PbTe samples, which goes down to much lower temperatures than ours, was fitted with a low order polynomial (solid-black line in Fig. A1). For the Na-doped samples, the data was fitted by keeping all the polynomial coefficient found for the undoped sample, except the zero-power term (vertical offset), which represents the zero-temperature lattice parameter for these Na-doped samples. The values obtained for the zero-temperature lattice parameter of these three compositions are summarized in Table AI. The temperature variation of the lattice parameter, from zero temperature to room temperature, of the samples studied here, is of the order of 0.5%, whereas the compositional variation, from undoped PbTe to 0.62% Na-doped PbTe, is of the order of 0.2%.

Appendix C: Volume dependence of DFT results

In this section we comment on the volume dependence of the band-structure and quantum-oscillation parameters in our DFT calculations. Table AII shows the vol-

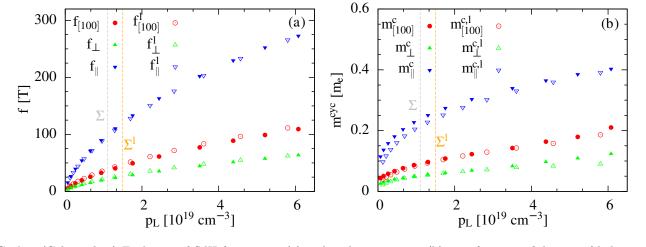


FIG. A2. (Color online) Evolution of SdH frequencies (a) and cyclotron masses (b) as a function of density of holes in the L-pocket, p_L , for two different volumes: 6.50 Å (open symbols and superscript l) and 6.44 Å (filled symbols and no superscript). The larger volume corresponds also to a larger band offset – 120 meV vs 74 meV. The dashed vertical lines indicate the L-pocket hole density above which the Σ -pockets start to be populated.

TABLE AII. Volume dependence of band-structure parameters in DFT. The volume range is chosen to cover the experimental range of (un)doped samples at T = 0 K. a is the lattice constant, and m^* are the effective masses (curvature) at the top of the valence band.

a [Å]	Band offset $[meV]$	$ m_{\perp}^{*} \ [m_{e}]$	$ m_{\parallel}^* \ [m_e]$
6.43	71	0.016	0.368
6.44	74	0.014	0.305
6.45	84	0.011	0.224

ume dependence of the band offset and effective masses for the range of experimental volumes of (un)doped samples at T = 0 K (see Fig. A1 and Table AI).

An increase in volume is accompanied by an increase in band offset (in contrast to the behavior expected from experiments, where thermal expansion leads to a decrease of the band offset^{17–19}), and a decrease in effective masses. The latter indicates that the L-pocket becomes narrower, but is not able alone to predict an appreciable change in the evolution of SdH frequencies and cyclotron masses, because, as mentioned in the main text, the band is non-parabolic. To check the influence of volume on SdH frequencies and cyclotron masses, we computed their evolution with doping for two different volumes (figure A2), the DFT-lattice constant 6.44 Å – with a band offset of 74 meV – and a representative larger one 6.50 Å (noted with an *l*-superscript in the figure) – with a band offset of 120 meV.

No appreciable differences in the doping dependence for the two different volumes can be observed: in fact, if the L-pocket is narrower it becomes filled faster, or, the shift in Fermi energy to obtain a given density of holes is larger. The concentration at which the Σ -pockets start contributing is also not much different for the same reason. We conclude that unit-cell volume changes of the order of those found experimentally (due to temperature and compositional variation) do not affect significantly our DFT results.

Appendix D: Cyclotron effective mass anisotropy

For a given dispersion relation one can, in principle, find the relation between the geometric anisotropy of the Fermi surface and the anisotropy of the cyclotron effective mass. For a perfect parabolic band, the general anisotropic dispersion relation is given by,

$$\frac{\hbar^2 k_x^2}{2m_x} + \frac{\hbar^2 k_y^2}{2m_y} + \frac{\hbar^2 k_z^2}{2m_z} = E \tag{D1}$$

where m_x , m_y and m_z are the band masses. For an ellipsoidal Fermi surface with the semi-major axis of the ellipse oriented along the z-axis, the band masses are $m_x = m_y = m_{\perp}$ (prolate ellipsoid) and $m_z = m_{\parallel}$. For such systems, the minimum and maximum cross-sectional areas are

$$A_{\perp} = \pi k_{x,y}^2 \Big|_{k_z=0} = \frac{2\pi m_{\perp}}{\hbar^2} E$$
 (D2a)

$$A_{\parallel} = \pi k_{x,y} \left| k_z \right|_{k_z = 0} k_z \left| k_{x,y} \right|_{k_x,y = 0} = \frac{2\pi}{\hbar^2} \sqrt{m_\perp m_\parallel} E \qquad (D2b)$$

and the ratio of maximum-to-minimum cross-sectional areas is

$$\frac{A_{\parallel}}{A_{\perp}} = \frac{f_{\max}}{f_{\min}} = \sqrt{\frac{m_{\parallel}}{m_{\perp}}} = \sqrt{K}$$
(D3)

where $K = m_{\parallel}/m_{\perp}$ is defined as the ratio of band masses, and it directly represents the anisotropy of the ellipsoidal pocket. As our experiment is a direct probe of cyclotron masses, we can find a relation between K and the extremal cyclotron masses. For a perfect parabolic band, with dispersion of the form given in Eq. D1, the cyclotron effective mass, $m^{cyc} = e|\vec{B}|/\hbar\omega_c$, for a magnetic field of the general form $\vec{B} = B_x \hat{x} + B_y \hat{y} + B_z \hat{z}$ can be found from the dynamic equations and the dispersion relation, resulting in the expression

$$m^{cyc} = \sqrt{\frac{m_x m_y m_z}{m_x \left(\frac{B_x}{|B|}\right)^2 + m_y \left(\frac{B_y}{|B|}\right)^2 + m_z \left(\frac{B_z}{|B|}\right)^2}} \quad (D4)$$

For an ellipsoid of revolution, therefore, the transverse and longitudinal cyclotron effective masses, in terms of the band masses, are

$$\begin{split} m_{\perp}^{cyc} &= m_{\perp} \qquad \text{(D5a)} \\ m_{\parallel}^{cyc} &= \sqrt{m_{\perp}m_{\parallel}} \,. \qquad \text{(D5b)} \end{split}$$

And with this,

$$\frac{m_{\parallel}^{cyc}}{m_{\perp}^{cyc}} = \sqrt{\frac{m_{\parallel}}{m_{\perp}}} = \sqrt{K} \,. \tag{D6}$$

For the case of $\operatorname{Pb}_{1-x}\operatorname{Na}_x\operatorname{Te}$, in which $K = 14.3 \pm 0.4$ for a wide range of dopings, $m_{\parallel}^{cyc}/m_{\perp}^{cyc} = 3.78 \pm 0.05$. Additionally, from Eq. D4, we can find a general expression for the angle dependence of cyclotron mass of an ellipsoid of revolution, with respect to the main axis of the ellipsoid, and as a function of the transverse cyclotron mass, by writing the components of the magnetic field in spherical coordinates as $B_x = |\vec{B}| \sin \theta \cos \varphi$, $B_y = |\vec{B}| \sin \theta \sin \varphi$ and $B_z = |\vec{B}| \cos \theta$:

$$\frac{m^{cyc}\left(\theta\right)}{m_{\perp}^{cyc}} = \sqrt{\frac{K}{\left(K-1\right)\cos^{2}\theta + 1}} \tag{D7}$$

Appendix E: Effective cyclotron mass along the [100] orientation

Figure A3 shows the temperature dependence of the oscillating component of magnetoresistance for $Pb_{1-x}Na_xTe$ samples of different Na concentrations, for field oriented along the [100] direction, which provides direct access to the $m_{[100]}^{cyc}$ cyclotron effective mass. Leastsquares fits to Eq. 1, including up to the second strongest frequency component, for each Na doping, and for a field range of 3-5 T to 14 T, are shown in the right-column plots of this figure. The obtained [100] cyclotron masses are summarized in Table II, and plotted as a function of carrier concentration in Fig. 16, in the discussion section.

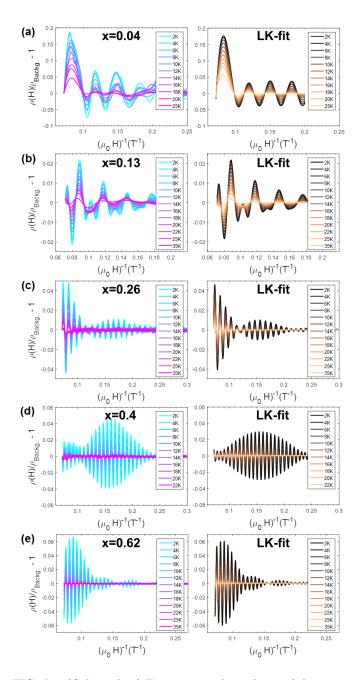


FIG. A3. (Color online) Temperature dependence of the amplitude of the oscillating component of magnetoresistance for $Pb_{1-x}Na_xTe$ samples, with magnetic field oriented in or close to the [100] direction. The left-column plots of each composition show the background-free data at different temperatures. The right-column plots show the fits of the data to the LK-formula in Eq. 1, using the two most dominant frequencies observed in the FFT of the lowest temperature curve (three most dominant for the x=0.62% sample). From these fits, the values of cyclotron effective mass and Dingle temperature, for each frequency term, are obtained.